

## ALTERNISTORS

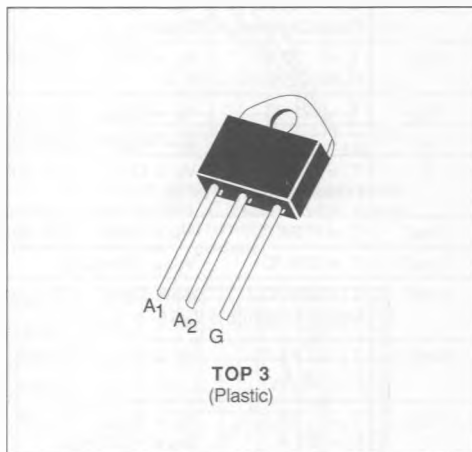
- $(di/dt)_c > 88 \text{ A/ms}$  (400 Hz)
- INSULATING VOLTAGE : 2500  $V_{RMS}$   
( $t \leq 1 \text{ mn}$  -  $F = 50 \text{ Hz}$ )
- UL RECOGNIZED (EB81734)

### APPLICATIONS

- POWER CONTROL ON INDUCTIVE LOAD  
(motor, transformer...)
- HIGH FREQUENCY OR HIGH  $(di/dt)_c$  LEVEL  
CIRCUITS

### DESCRIPTION

New range of solid state AC - switches with very high commutating capability.



### ABSOLUTE RATINGS (limiting values)

| Symbol             | Parameter                                        |                           | Value                      | Unit                   |
|--------------------|--------------------------------------------------|---------------------------|----------------------------|------------------------|
| $I_{T(RMS)}$       | RMS on-state Current (360° conduction angle)     | $T_C = 75^\circ \text{C}$ | 25                         | A                      |
| $I_{TSM}$          | Non Repetitive Surge Peak on-state Current       | $t = 10 \text{ ms}$       | 230                        | A                      |
|                    |                                                  | $t = 8.3 \text{ ms}$      | 250                        |                        |
|                    |                                                  | $t = 2.5 \text{ ms}$      | 390                        |                        |
| $I^2t$             | $I^2t$ Value for Fusing                          | $t = 10 \text{ ms}$       | 265                        | $\text{A}^2\text{s}$   |
| $di/dt$            | Critical Rate of Rise of on-state Current (1)    |                           | 100                        | $\text{A}/\mu\text{s}$ |
| $T_{stg}$<br>$T_j$ | Storage and Operating Junction Temperature Range |                           | - 40 to 125<br>- 40 to 125 | $^\circ\text{C}$       |

| Symbol    | Parameter                             | TPDV |     |     |     |     |      |      | Unit |
|-----------|---------------------------------------|------|-----|-----|-----|-----|------|------|------|
|           |                                       | 125  | 225 | 425 | 625 | 825 | 1025 | 1225 |      |
| $V_{DRM}$ | Repetitive Peak off-state Voltage (2) | 100  | 200 | 400 | 600 | 800 | 1000 | 1200 | V    |

(1)  $I_G = 1.5 \text{ A}$   $di/dt = 1 \text{ A}/\mu\text{s}$

(2)  $T_j = 125^\circ \text{C}$ .

### THERMAL RESISTANCES

| Symbol                   | Parameter                                                          | Value | Unit                      |
|--------------------------|--------------------------------------------------------------------|-------|---------------------------|
| $R_{TH(j-a)}$            | Junction to Ambient                                                | 50    | $^\circ\text{C}/\text{W}$ |
| $R_{TH(c-h)}$            | Contact (case-heatsink) with Grease                                | 0.15  | $^\circ\text{C}/\text{W}$ |
| $R_{TH(j-c)} \text{ DC}$ | Junction to Case for DC                                            | 2.09  | $^\circ\text{C}/\text{W}$ |
| $R_{TH(j-c)} \text{ AC}$ | Junction to Case for 360° Conduction Angle ( $F = 50 \text{ Hz}$ ) | 1.56  | $^\circ\text{C}/\text{W}$ |

GATE CHARACTERISTICS (maximum values)

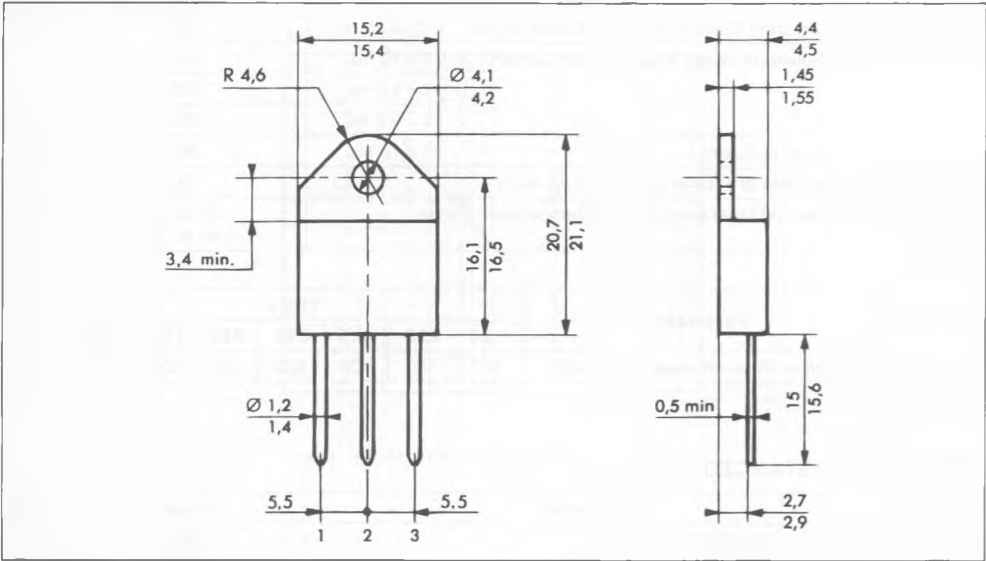
$P_{GM} = 40\text{ W}$  ( $t_p = 10\text{ }\mu\text{s}$ )       $I_{GM} = 8\text{ A}$  ( $t_p = 10\text{ }\mu\text{s}$ )  
 $P_{G(AV)} = 1\text{ W}$        $V_{GM} = 16\text{ V}$  ( $t_p = 10\text{ }\mu\text{s}$ )

ELECTRICAL CHARACTERISTICS

| Symbol        | Test Conditions                                                                                                                   | Quadrants                              | Min. | Typ. | Max. | Unit             |
|---------------|-----------------------------------------------------------------------------------------------------------------------------------|----------------------------------------|------|------|------|------------------|
| $I_{GT}$      | $T_j = 25\text{ }^\circ\text{C}$ $V_D = 12\text{ V}$ $R_L = 33\text{ }\Omega$<br>Pulse Duration $> 20\text{ }\mu\text{s}$         | I-II-III                               |      |      | 150  | mA               |
| $V_{GT}$      | $T_j = 25\text{ }^\circ\text{C}$ $V_D = 12\text{ V}$ $R_L = 33\text{ }\Omega$<br>Pulse Duration $> 20\text{ }\mu\text{s}$         | I-II-III                               |      |      | 1.5  | V                |
| $V_{GD}$      | $T_j = 125\text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $R_L = 3.3\text{ k}\Omega$                                                      | I-II-III                               | 0.2  |      |      | V                |
| $I_H^*$       | $T_j = 25\text{ }^\circ\text{C}$ $I_T = 500\text{ mA}$ Gate Open                                                                  |                                        |      | 50   |      | mA               |
| $I_L$         | $T_j = 25\text{ }^\circ\text{C}$ $V_D = 12\text{ V}$ $I_G = 300\text{ mA}$<br>Pulse Duration $> 20\text{ }\mu\text{s}$            | I-III                                  |      | 50   |      | mA               |
|               |                                                                                                                                   | II                                     |      | 100  |      |                  |
| $V_{TM}^*$    | $T_j = 25\text{ }^\circ\text{C}$ $I_{TM} = 35\text{ A}$ $t_p = 10\text{ ms}$                                                      |                                        |      |      | 1.8  | V                |
| $I_{DRM}^*$   | $T_j = 125\text{ }^\circ\text{C}$ $V_{DRM}$ Specified                                                                             |                                        |      |      | 8    | mA               |
| $dv/dt^*$     | $T_j = 125\text{ }^\circ\text{C}$ Gate Open<br>Linear Slope up to $V_D = 67\% V_{DRM}$                                            | $V_{DRM} \leq 800\text{ V}$            | 500  |      |      | V/ $\mu\text{s}$ |
|               |                                                                                                                                   | $V_{DRM} \geq 1000\text{ V}$           | 250  |      |      |                  |
| $(di/dt)_c^*$ | $T_C = 75\text{ }^\circ\text{C}$ $V_D = V_{DRM}$<br>$I_T = 35\text{ A}$                                                           | $(dv/dt)_c = 200\text{ V}/\mu\text{s}$ | 20   |      |      | A/ms             |
|               |                                                                                                                                   | $(dv/dt)_c = 10\text{ V}/\mu\text{s}$  | 88   |      |      |                  |
| $t_{gi}$      | $T_j = 25\text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 35\text{ A}$<br>$I_G = 0.5\text{ A}$ $di_G/dt = 3.5\text{ A}/\mu\text{s}$ | I-II-III                               |      | 2.5  |      | $\mu\text{s}$    |

\* For either polarity of electrode  $A_2$  voltage with reference to electrode  $A_1$ .

PACKAGE MECHANICAL DATA : TOP 3 Plastic



Cooling method : by conduction (method C)  
Marking : type number  
Weight : 5 g

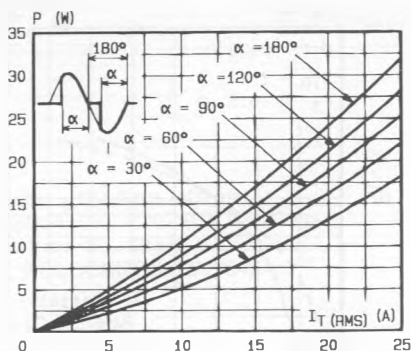


Fig.1 - Maximum mean power dissipation versus RMS on-state current.

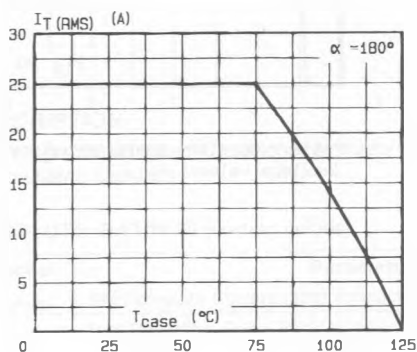


Fig.3 - RMS on-state current versus case temperature.

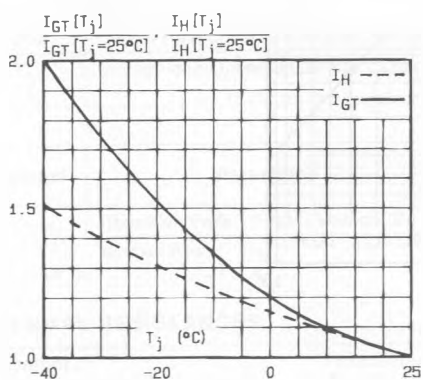


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

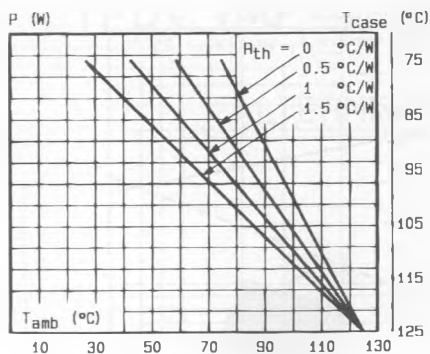


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for different thermal resistances heatsink + contact.

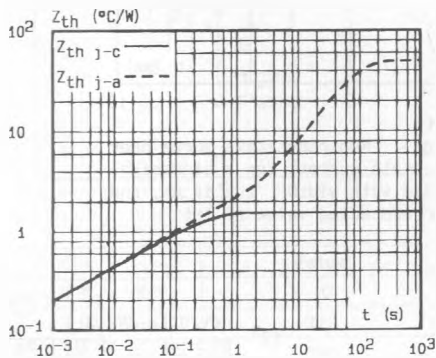


Fig.4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

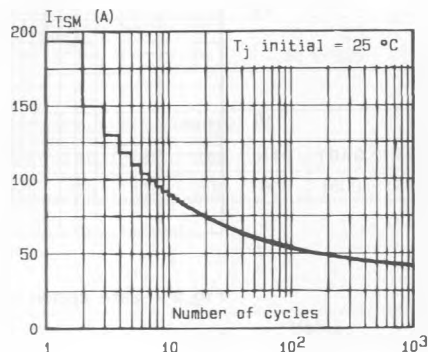


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

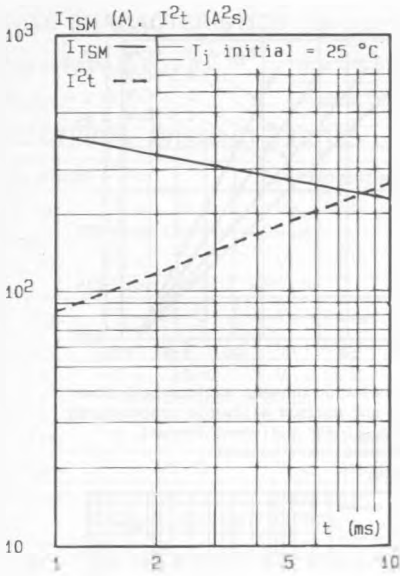


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

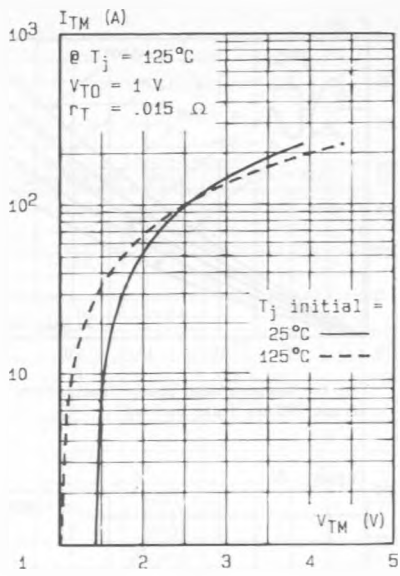


Fig.8 - On-state characteristics (maximum values).

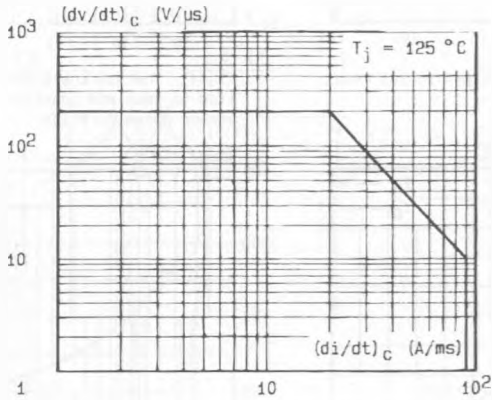


Fig.9 - Safe operating area.